

UM2176 User manual

STEVAL-IPMNG3Q motor control power board based on the SLLIMM-nano™ 2nd series of IGBT IPMs

Introduction

The STEVAL-IPMNG3Q is a compact motor drive power board based on SLLIMM-nano™ (small low-loss intelligent molded module) 2nd series (STGIPQ3H60T-HZ). It provides an affordable and easy-to-use solution for driving high power motors for a wide range of applications such as power white goods, air conditioning, compressors, power fans, high-end power tools and 3-phase inverters for motor drives in general. The IPM itself consists of short-circuit rugged IGBTs and a wide range of features like undervoltage lockout, smart shutdown, embedded temperature sensor and NTC, and overcurrent protection.

The main characteristics of this evaluation board are small size, minimal BOM and high efficiency. It consists of an interface circuit (BUS and $V_{\rm CC}$ connectors), bootstrap capacitors, snubber capacitor, hardware short-circuit protection, fault event and temperature monitoring. In order to increase the flexibility, it is designed to work in single- or three-shunt configuration and with triple current sensing options: three dedicated onboard op-amps, an internal IPM op-amp and op-amps embedded in the MCU. The Hall/Encoder section completes the circuit.

With these advanced characteristics, the system is designed to achieve fast and accurate current feedback conditioning, satisfying the typical requirements for field-oriented control (FOC).

The STEVAL-IPMNG3Q is compatible with ST's STM32-based control board, enabling designers to build a complete platform for motor control.



Figure 1: Motor control board (top view) based on SLLIMM-nano™ 2nd series

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UM2176 Key features

1 Key features

- Input voltage: 125 400 V_{DC}
 Nominal power: up to 300 W
 Nominal current: up to 1.8 A
- Input auxiliary voltage: up to 20 V_{DC}
- Motor control connector (32 pins) interfacing with ST MCU boards
- Single- or three-shunt resistors for current sensing (with sensing network)
- Three options for current sensing: external dedicated op-amps, internal SLLIMM-nano op-amp (single) or through MCU
- Overcurrent hardware protection
- IPM temperature monitoring and protection
- Hall sensors (3.3 / 5 V)/encoder inputs (3.3 / 5 V)
- IGBT intelligent power module:
 - SLLIMM-nano[™] 2nd series IPM (STGIPQ3H60T-HZ Full molded package package)
- Universal design for further evaluation with bread board and testing pins
- Very compact size

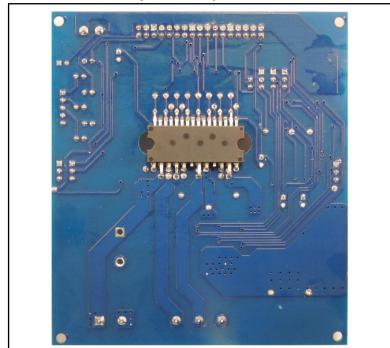


Figure 2: Motor control board (bottom view) based on SLLIMM-nano™ 2nd series

Circuit schematics UM2176

2 Circuit schematics

The full schematics for the SLLIMM-nano™ 2nd series card for STGIPQ3H60T-HZ IPM products is shown below. This card consists of an interface circuit (BUS and V_{CC} connectors), bootstrap capacitors, snubber capacitor, short-circuit protection, fault output circuit, temperature monitoring, single-/three-shunt resistors and filters for input signals. It also includes bypass capacitors for V_{CC} and bootstrap capacitors. The capacitors are located very close to the drive IC to avoid malfunction due to noise.

Three current sensing options are provided: three dedicated onboard op-amps, one internal IPM op-amp and the embedded MCU op-amps; selection is performed through three jumpers.

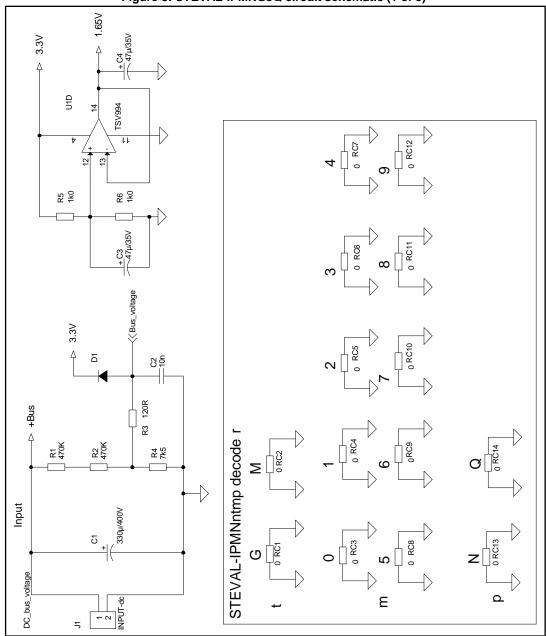
The Hall/Encoder section (powered at 5 V or 3.3 V) completes the circuit.



UM2176 Circuit schematics

2.1 Schematic diagrams

Figure 3: STEVAL-IPMNG3Q circuit schematic (1 of 5)



Circuit schematics UM2176

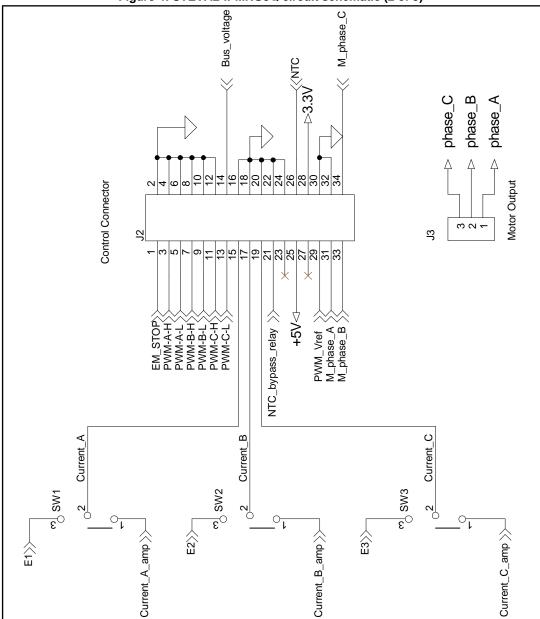


Figure 4: STEVAL-IPMNG3Q circuit schematic (2 of 5)

UM2176 Circuit schematics

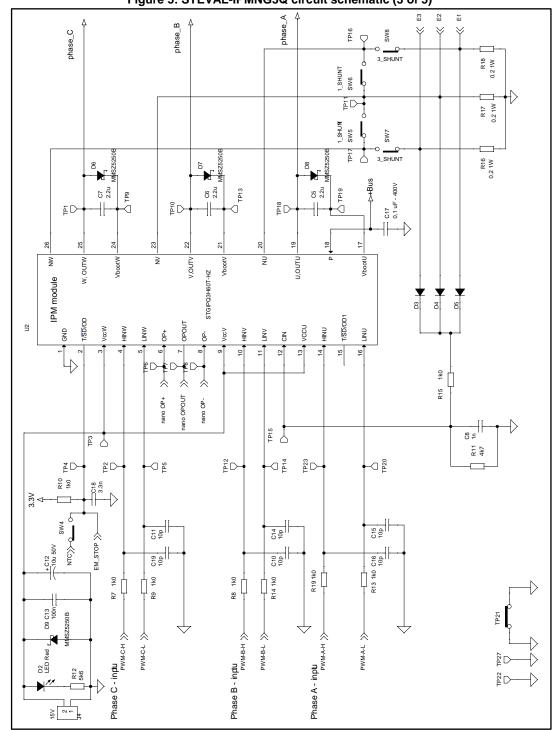


Figure 5: STEVAL-IPMNG3Q circuit schematic (3 of 5)

Circuit schematics UM2176

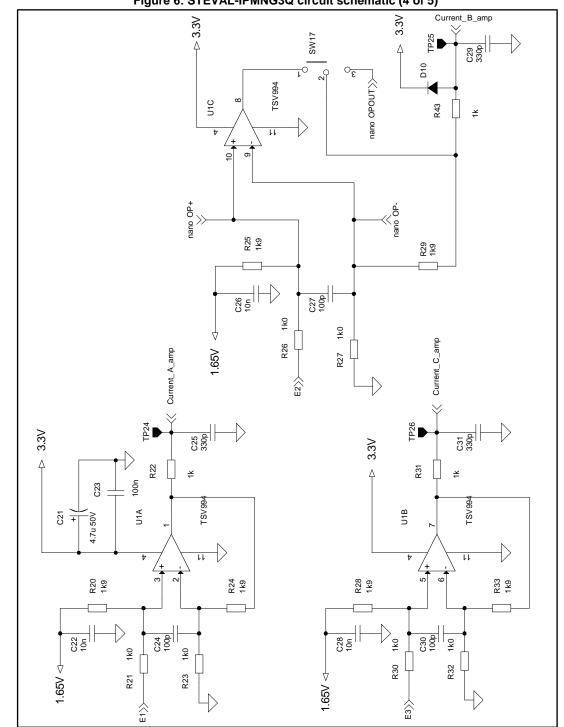


Figure 6: STEVAL-IPMNG3Q circuit schematic (4 of 5)

UM2176 Circuit schematics

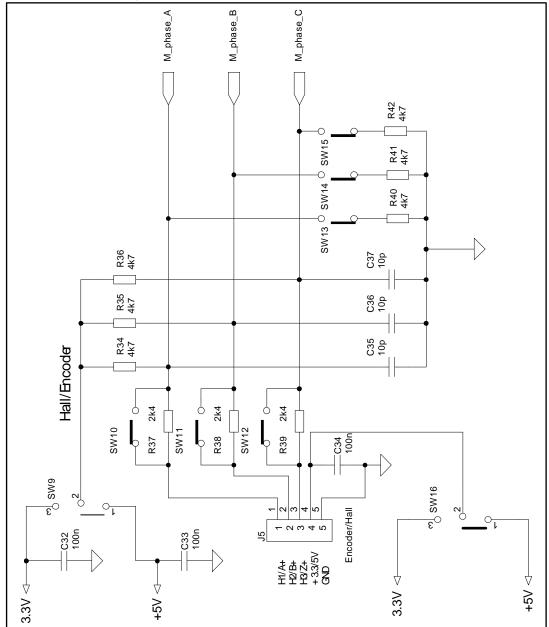


Figure 7: STEVAL-IPMNG3Q circuit schematic (5 of 5)

Main characteristics UM2176

3 Main characteristics

The board is designed for a 125 V_{DC} to 400 V_{DC} supply voltage.

An appropriate bulk capacitor for the power level of the application must be mounted at the dedicated position on the board.

The SLLIMM-nano integrates six IGBT switches with freewheeling diodes and high voltage gate drivers. Thanks to this integrated module, the system offers power inversion in a simple and compact design that requires less PCB area and increases reliability.

The board offers the added flexibility of being able to operate in single- or three-shunt configuration by modifying solder bridge jumper settings (see Section 4.3.4: "Single- or three-shunt selection").

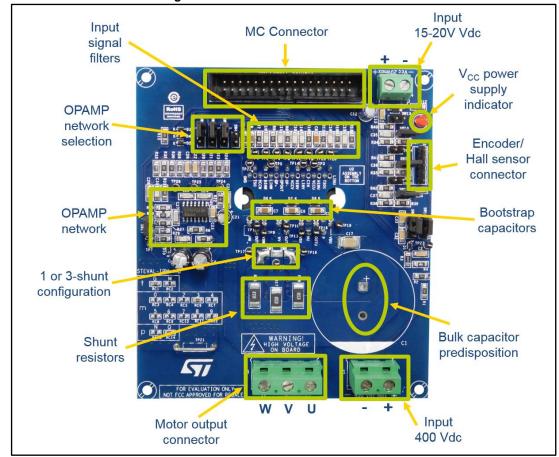


Figure 8: STEVAL-IPMNG3Q architecture

4 Filters and key parameters

4.1 Input signals

The input signals (LINx and HINx) to drive the internal IGBTs are active high. A 375 k Ω (typ.) pull-down resistor is built-in for each input signal. To prevent input signal oscillation, an RC filter is added on each input as close as possible to the IPM. The filter is designed using a time constant of 10 ns (1 k Ω and 10 pF).

4.2 Bootstrap capacitor

In the 3-phase inverter, the emitters of the low side IGBTs are connected to the negative DC bus (V_{DC-}) as common reference ground, which allows all low side gate drivers to share the same power supply, while the emitter of the high side IGBTs is alternately connected to the positive (V_{DC-}) and negative (V_{DC-}) DC bus during running conditions.

A bootstrap method is a simple and cheap solution to supply the high voltage section. This function is normally accomplished by a high voltage fast recovery diode. The SLLIMM-nano 2nd series family includes a patented integrated structure that replaces the external diode with a high voltage DMOS functioning as a diode with series resistor. An internal charge pump provides the DMOS driving voltage.

The value of the C_{BOOT} capacitor should be calculated according to the application requirements.

Figure 9: "CBOOT graph selection" shows the behavior of C_{BOOT} (calculated) versus switching frequency (f_{sw}), with different values of ΔV_{CBOOT} for a continuous sinusoidal modulation and a duty cycle δ = 50%.



This curve is taken from application note AN4840 (available on www.st.com); calculations are based on the STGIP5C60T-Hyy device, which represents the worst case scenario for this kind of calculation.

The boot capacitor must be two or three times larger than the C_{BOOT} calculated in the graph.

For this design, a value of 2.2 µF was selected.



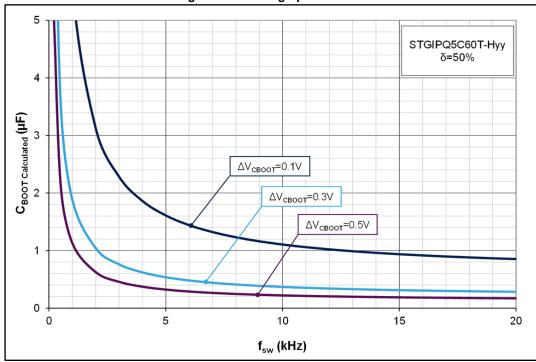


Figure 9: CBOOT graph selection

4.3 Overcurrent protection

The SLLIMM-nano 2^{nd} series integrates a comparator for fault sensing purposes. The comparator has an internal voltage reference V_{REF} (540 mV typ.) connected to the inverting input, while the non-inverting input on the CIN pin can be connected to an external shunt resistor to implement the overcurrent protection function. When the comparator triggers, the device enters the shutdown state.

The comparator output is connected to the SD pin in order to send the fault message to the MCU.

4.3.1 SD pin

The SD is an input/output pin (open drain type if used as output) used for enable and fault; it is shared with NTC thermistor, internally connected to GND.

The pull-up resistor (R10) causes the voltage V_{SD} -GND to decrease as the temperature increases. To maintain the voltage above the high-level logic threshold, the pull-up resistor is sized at 1 k Ω (3.3 V MCU power supply).

The filter on SD (R10 and C18) must be sized to obtain the desired re-starting time after a fault event and placed as close as possible to the pin.

A shutdown event can be managed by the MCU; in which case, the SD functions as the input pin.

Conversely, the SD functions as an output pin when an overcurrent or undervoltage condition is detected.

4.3.2 Shunt resistor selection

The value of the shunt resistor is calculated by the following equation:

Equation 1

$$R_{SH} = \frac{V_{ref}}{I_{OC}}$$

Where V_{ref} is the internal comparator (CIN) (0.54 V typ.) and I_{OC} is the overcurrent threshold detection level.

The maximum OC protection level should be set to less than the pulsed collector current in the datasheet. In this design the over current threshold level was fixed at Ioc = 3.9 A in order to select a commercial shunt resistor value.

Equation 2

$$R_{SH} = \frac{V_{ref} \cdot \left(\frac{R15 + R11}{R11}\right) + V_F}{I_{OC}} = \frac{0.54 \cdot \left(\frac{1000 + 4700}{4700}\right) + 0.18}{3.9} = 0.214\Omega$$

Where V_F is the voltage drop across diodes D3, D4 and D5.

For the power rating of the shunt resistor, the following parameters must be considered:

- Maximum load current of inverter (85% of Inom [Arms]): Iload(max).
- Shunt resistor value at $T_C = 25$ °C.
- Power derating ratio of shunt resistor at T_{SH} =100 °C
- Safety margin.

The power rating is calculated by following equation:

Equation 3

$$P_{SH} = \frac{1}{2} \cdot \frac{I_{load(\text{max})}^2 \cdot R_{SH} \cdot margin}{Derating\ ratio}$$

For the STGIPQ3H60T-HZ, where $R_{SH} = 0.2 \Omega$:

- $I_{nom} = 3A \rightarrow I_{nom[rms]} = \frac{I_{nom}}{\sqrt{2}} \rightarrow I_{load(max)} = 85\% (I_{nom[rms]}) = 1.8 A_{rms}$ Power derating ratio of shunt resistor at T_{SH} = 100 °C: 80% (from datasheet
- manufacturer)
- Safety margin: 30%

Equation 4

$$P_{SH} = \frac{1}{2} \cdot \frac{1.8^2 \cdot 0.2 \cdot 1.3}{0.8} = 0.52 W$$

Considering available commercial values, a 2 W shunt resistor was selected.

Based on the previous equations and conditions, the minimum shunt resistance and power rating is summarized below.

Table 1: Shunt selection

Device	I _{nom (peak)}	OCP _(peak) [A]	I _{load(max)} [Arms]	R _{SHUNT} [Ω]	Minimum shunt power rating Р _{SH} [W]
STGIPQ3H60T- HZ	3	4.2	1.8	0.2	0.52



4.3.3 CIN RC filter

An RC filter network on the CIN pin is required to prevent short-circuits due to the noise on the shunt resistor. In this design, the R15-C8 RC filter has a constant time of about 1 μ s.

4.3.4 Single- or three-shunt selection

Single- or three-shunt resistor circuits can be adopted by setting the solder bridges SW5, SW6, SW7 and SW8.

The figures below illustrate how to set up the two configurations.





Figure 11: Three-shunt configuration



Further details regarding sensing configuration are provided in the next section.

5 Current sensing amplifying network

The STEVAL-IPMNG3Q motor control demonstration board can be configured to run in three-shunt or single-shunt configurations for field oriented control (FOC).

The current can be sensed thanks to the shunt resistor and amplified by using the on-board operational amplifiers or by the MCU (if equipped with op-amp).

Once the shunt configuration is chosen by setting solder bridge on SW5, SW6, SW7 and SW8 (as described in *Section 4.3.4: "Single- or three-shunt selection"*), the user can choose whether to send the voltage shunt to the MCU amplified or not amplified.

Single-shunt configuration requires a single op amp so the only voltage sent to the MCU to control the sensing is connected to phase V through SW2.

SW1, SW2, SW3 and SW17 can be configured to select which signals are sent to the microcontroller, as per the following table.

Bridge Bridge **Bridge** Bridge Configuration Sensing (SW1) (SW2) (SW3) (SW17) IPM op-amp 1-2 2-3 open open On board op-Single Shunt 1-2 open 1-2 open amp MCU op-amp 2-3 1-2 open open On board op-1-2 1-2 1-2 1-2 amp Three Shunt MCU op-amp 2-3 2-3 2-3 1-2

Table 2: Op-amp sensing configuration

The operational amplifier TSV994 used on the amplifying networks has a 20 MHz gain bandwidth from a single positive supply of 3.3 V.

The amplification network must allow bidirectional current sensing, so an output offset $V_0 = +1.65 \text{ V}$ represents zero current.

For the STGIPQ3H60T-HZ ($I_{OCP} = 4.2$ A; $R_{SHUNT} = 0.2$ Ω), the maximum measurable phase current, considering that the output swings from +1.65 V to +3.3 V (MCU supply voltage) for positive currents and from +1.65 V to 0 for negative currents is:

Equation 5

$$MaxMeasCurrent = rac{\Delta V}{r_m} = 4.2 \, A$$
 $r_m = rac{\Delta V}{MaxMeasCurrent} = rac{1.65}{4.2} = 0.39 \, \Omega$

The overall trans-resistance of the two-port network is:

$$r_m = R_{SHUNT} \cdot AMP = 0.2 \cdot AMP = 0.39 \Omega$$

$$AMP = \frac{r_m}{R_{SHUNT}} = \frac{0.39}{0.2} = 1.96$$

Finally choosing R_a=R_b and R_c=R_d, the differential gain of the circuit is:

$$AMP = \frac{R_c}{R_a} = 1.9$$



An amplification gain of 1.9 was chosen. The same amplification is obtained for all the other devices, taking into account the OCP current and the shunt resistance, as described in *Table 1: "Shunt selection"*.

The RC filter for output amplification is designed to have a time constant that matches noise parameters in the range of 1.5 µs:

$$4 \cdot \tau = 4 \cdot R_e \cdot C_c = 1.5 \ \mu s$$

$$C_c = \frac{1.5 \ \mu s}{4 \cdot 1000} = 375 \ pF(330 \ pF \ selected)$$

Table 3: Amplifying networks

Dhaoa		Amplifyin	g network		RC f	filter
Phase	Ra	Rb	Rc	Rd	Re	Сс
Phase U	R21	R23	R20	R24	R22	C25
Phase V	R26	R27	R25	R29	R43	C29
Phase W	R30	R32	R28	R33	R31	C31

6 Temperature monitoring

The SLLIMM-nano 2nd series family integrates an NTC thermistor placed close to the power stage. The board is designed to use it in sharing with the SD pin. Monitoring can be enabled and disabled via the SW4 switch.

6.1 NTC Thermistor

The built-in thermistor (85 k Ω at 25 °C) is inside the IPM and connected on \overline{SD} /OD pin2 (shared with the SD function).

Given the NTC characteristic and the sharing with the \overline{SD} function, the network is designed to keep the voltage on this pin higher than the minimum voltage required for the pull up voltage on this pin over the whole temperature range.

Considering $V_{bias} = 3.3 \text{ V}$, a pull up resistor of 1 k Ω (R10) was used.

The figure below shows the typical voltage on this pin as a function of device temperature.

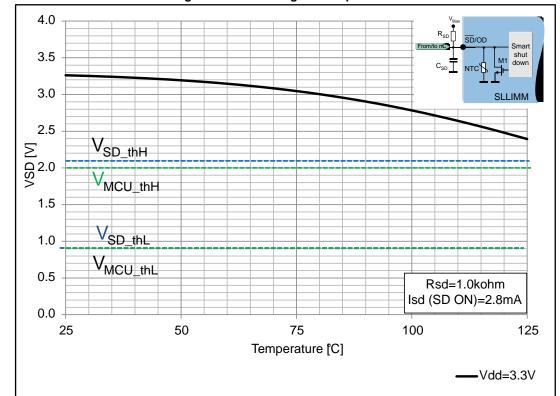


Figure 12: NTC voltage vs temperature

7 Firmware configuration for STM32 PMSM FOC SDK

The following table summarizes the parameters which customize the latest version of the ST FW motor control library for permanent magnet synchronous motors (PMSM): STM32 PMSM FOC SDK for this STEVAL-IPMNG3Q.

Table 4: ST motor control workbench GUI parameters - STEVAL-IPMNG3Q

Block	Parameter	Value	
	Comparator threshold	$V_{ref} \cdot \left(\frac{R15 + R11}{R11}\right) + V_F = 0.83 V$	
Over current protection	Overcurrent network offset	0	
	Overcurrent network gain	0.1 V/A	
Bus voltage sensing	Bus voltage divider	1/125	
	Min rated voltage	125 V	
Rated bus voltage info	Max rated voltage	400 V	
	Nominal voltage	325 V	
	Current reading typology	Single- or three-shunt	
Current sensing	Shunt resistor value	0.2 Ω	
	Amplifying network gain	1.9	
	Phase U Driver	HS and LS: Active high	
Command stage	Phase V Driver	HS and LS: Active high	
	Phase W Driver	HS and LS: Active high	

8 Connectors, jumpers and test pins

Table 5: Connectors

	Table 5: Connectors					
Connector	Description / pinout					
J1	Supply connector (DC – 125 V to 400 V) 1-L - phase 2 N - neutral					
	Motor control connector					
	1 - emergency stop 3 - PWM-1H 5 - PWM-1L	2 - GND 4 - GND 6 - GND				
	7 - PWM-2H	8 - GND				
	9 - PWM-2L	10 - GND				
	11 - PWM-3H	12 - GND				
	13 - PWM-3L	14 - HV bus voltage				
J2	15 - current phase A	16 - GND				
J2	17 - current phase B	18 - GND				
	19 - current phase C	20 - GND				
	21 - NTC bypass relay	22 - GND				
	23 - dissipative brake PWM	24 - GND				
	25 - +V power	26 - heat sink temperature				
	27- PFC sync.	28 - VDD_m				
	29 - PWM VREF	30 - GND				
	31 - measure phase A	32 - GND				
	33 - measure phase B 34 - measure phase C					
J3	Motor connector • phase A • phase B • phase C					
J4	VCC supply (20 VDC max) • positive • negative					
J5	Hall sensors / encoder input connector 1. Hall sensors input 1 / encoder A+ 2. Hall sensors input 2 / encoder B+ 3. Hall sensors input 3 / encoder Z+ 4. 3.3 or 5 Vdc 5. GND					



Table 6: Jumpers

Jumper	Description				
	Choose current U to send to control board:				
SW1	Jumper on 1-2: from amplification				
	Jumper on 2-3: directly from motor output				
	Choose current V to send to control board				
SW2	Jumper on 1-2: from amplification				
	Jumper on 2-3: directly from motor output				
	Choose current W to send to control board:				
SW3	Jumper on 1-2: from amplification				
	Jumper on 2-3: directly from motor output				
SW4	Enable or disable sending temperature information from NTC to microcontroller				
	Choose 1-shunt or 3-shunt configuration. (through solder bridge)				
SW5, SW6	SW5, SW6 closed				
SW7, SW8	SW7, SW8 open	one shunt			
	SW5, SW6 open	three shunt			
	SW7, SW8 closed				
	Choose input power for Hall/Encoder				
SW9, SW16	Jumper on 1-2: 5 V				
	Jumper on 2-3: 3.3 V				
SW10, SW13	Modify phase A hall sensor network				
SW11, SW14	Modify phase B hall sensor network				
SW12, SW15	Modify phase C hall sensor network				
	Choose on-board or IPM op-amp in one shunt con	figuration			
SW17	Jumper on 1-2: on-board op-amp				
	Jumper on 2-3: IPM op-amp				

Table 7: Test pins

TP1 OUTW TP2 HINW (high side W control signal input) TP3 VccW TP4 SD (shutdown pin)/NTC TP5 LINW (high side W control signal input) TP6 OP+ TP7 OPOUT TP8 OP- TP9 VbootW TP10 OUTV TP11 NV TP12 HINV (high side V control signal input) TP13 VbootV TP14 LINV (high side V control signal input) TP15 CIN TP16 NU TP17 NW TP18 OUTU TP18 OUTU TP19 VbootU TP19 VbootU TP20 LINU (high side U control signal input) TP21 Ground TP22 Ground TP22 Ground TP23 HinU (high side U control signal input) TP24 Current_A_amp	Test Pin	Description
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TP14 LINV (high side V control signal input) TP15 CIN TP16 NU TP17 NW TP18 OUTU TP19 VbootU TP20 LINU (high side U control signal input) TP21 Ground TP22 Ground TP23 HinU (high side U control signal input) TP24 Current_A_amp	TP12	HINV (high side V control signal input)
TP15 CIN TP16 NU TP17 NW TP18 OUTU TP19 VbootU TP20 LINU (high side U control signal input) TP21 Ground TP22 Ground TP23 HinU (high side U control signal input) TP24 Current_A_amp	TP13	VbootV
TP16 NU TP17 NW TP18 OUTU TP19 VbootU TP20 LINU (high side U control signal input) TP21 Ground TP22 Ground TP23 HinU (high side U control signal input) TP24 Current_A_amp	TP14	LINV (high side V control signal input)
TP17 NW TP18 OUTU TP19 VbootU TP20 LINU (high side U control signal input) TP21 Ground TP22 Ground TP23 HinU (high side U control signal input) TP24 Current_A_amp	TP15	CIN
TP18 OUTU TP19 VbootU TP20 LINU (high side U control signal input) TP21 Ground TP22 Ground TP23 HinU (high side U control signal input) TP24 Current_A_amp	TP16	NU
TP19 VbootU TP20 LINU (high side U control signal input) TP21 Ground TP22 Ground TP23 HinU (high side U control signal input) TP24 Current_A_amp	TP17	NW
TP20 LINU (high side U control signal input) TP21 Ground TP22 Ground TP23 HinU (high side U control signal input) TP24 Current_A_amp	TP18	OUTU
TP21 Ground TP22 Ground TP23 HinU (high side U control signal input) TP24 Current_A_amp	TP19	VbootU
TP22 Ground TP23 HinU (high side U control signal input) TP24 Current_A_amp	TP20	LINU (high side U control signal input)
TP23 HinU (high side U control signal input) TP24 Current_A_amp	TP21	Ground
TP24 Current_A_amp	TP22	Ground
7.7	TP23	HinU (high side U control signal input)
TDOS Command D. Comm	TP24	Current_A_amp
IP25 Current_B_amp	TP25	Current_B_amp
TP26 Current_C_amp	TP26	Current_C_amp
TP27 Ground	TP27	Ground



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9 Bill of materials

Table 8: Bill of materials

Item	Q. ty	Ref.	Part/Value	Description	Manufacturer	Order code
1	1	C1	330 μF 400 V ±10%	Electrolytic Capacitor	EPCOS	B4350 1A933 7M000
2	5	C2, C22, C26, C28	10 nF 50 V ±10%	Ceramic Multilayer Capacitors	AVX	12065 C103K AT2A
3	2	C3, C4	47 μF 50 V ±20%	Electrolytic Capacitor	any	any
4	3	C5, C6, C7	2.2 μF 25V ±10%	Ceramic Multilayer Capacitors	Murata	GCM3 1MR71 E225K A57L
5	1	C17	0.1 μF 630V ±10%	Ceramic Multilayer Capacitors	Murata	GRM4 3DR72 J104K W01L
6	9	C10,C11,C14, C15,C16, C19,C35,C36, C37	10 pF 100 V ±10%	Ceramic Multilayer Capacitors	AVX	12061 A100J AT2A
7	5	C13,C23,C32, C33,C34	100 nF 50 V ±10%	Ceramic Multilayer Capacitors	AVX	12065 C104K AZ2A
8	1	C8	1 nF 50 V ±10%	Ceramic Multilayer Capacitors	Kemet	C1206 C102K 5RACT U
9	1	C12	10 μF 50 V ±20%	Electrolytic Capacitor	any	any
10	1	C18	3.3 nF 50 V ±10%	Ceramic Multilayer Capacitors	Kemet	C1206 C332K 5RACT U
11	3	C24,C27,C30	100 pF 100 V ±10%	Ceramic Multilayer Capacitors	Kemet	C1206 C101J 1GACT U
12	3	C25,C29,C31	330 pF 50 V ±10%	Ceramic Multilayer Capacitors	AVX	12065 A331J AT2A
13	1	C21	4.7 μF 50 V ±20%	Electrolytic Capacitor	any	any
14	5	D1,D3,D4,D5, D10	Diode BAT48J	-	ST	BAT48 J

UM2176 Bill of materials

Item	Q. ty	Ref.	Part/Value	Description	Manufacturer	Order code
15	4	D6,D7,D8,D9	Diode ZENER 20 V 5	-	Fairchild Semiconductor	MMSZ 5250B
16	1	D2	LED Red	-	Ledtech	L4RR3 000G1 EP4
17	1	J1	Conector - 7.62 mm - 2P 300 V	-	TE Connectivity AMP Connectors	282845 -2
18	1	J2	Connector 34P	-	RS	625- 7347
19	1	J3	Connector - 7,62 mm - 3P 400 V	-	TE Connectivity AMP Connectors	282845 -3
20	1	J4	Connector - 5 mm - 2P 50 V	-	Phoenix Contact	172912 8
21	1	J5	Connector - 2.54 mm - 5P 63 V	-	RS	W8113 6T382 5RC
22	2	R1,R2	470 kΩ 400 V ±1%	metal film SMD resistor	any	any
23	1	R3	120 Ω 400 V ±1%	metal film SMD resistor	any	any
24	1	R4	7.5 kΩ 400 V ±1%	metal film SMD resistor	Panasonic	ERJP0 8F750 1V
25	19	R5,R6,R7,R8, R9, R10,R13,R14, R15,R19, R21,R22,R23, R26,R27, R30,R31,R32, R43	1 kΩ 25 V ±1%	metal film SMD resistor	any	any
26	1	R12	5.6 kΩ 25 V ±1%	metal film SMD resistor	any	any
27	3	R16,R17,R18	0.2 Ω	metal film SMD resistor	Vishay / Dale	WSL25 12R20 00FEA
28	6	R20,R24,R25, R28,R29, R33	1.9 kΩ		any	any
29	3	R37,R38,R39	2.4 kΩ 25 V ±1%	metal film SMD resistor	any	any
30	7	R11,R34,R35, R36,R40, R41,R42	4.7 kΩ 25 V ±1%	metal film SMD resistor	any	any
31	3	RC1,RC6, RC14	0 Ω any		any	any



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Item	Q. ty	Ref.	Part/Value	Description	Manufacturer	Order code
32	11	RC2,RC3,RC4 ,RC5,RC7, RC8,RC9,RC1 0,RC11,RC12, RC13	DNM			
33	2	SW7,SW8	Solder Bridge	-	-	-
34	2	SW5,SW6	open	-	-	-
35	6	SW1,SW2,SW 3,SW9, SW16,SW17	Jumper 2.54	-	RS	W8113 6T382 5RC
36	7	SW4,SW10,S W11,SW12, SW13,SW14,S W15	Jumper 2.54	-	RS	W8113 6T382 5RC
37	26	TP1,TP2,TP3, TP4,TP5, TP6,TP7,TP8, TP9,TP10, TP11,TP12,TP 13,TP14,TP15, , TP16,TP17,TP 18,TP19,TP20, , TP22,TP23,TP 24,TP25,TP26, , TP27	PCB terminal 1mm	-	KEYSTONE	5001
38	26	TP22,TP27	PCB terminal 1 mm	-	KEYSTONE	5001
39	1	TP21	PCB terminal 12.7mm		HARWIN	D3083 B-46
40	13	to close SWxy	Jumper TE Connectivity female straight, Black, 2-way, 2.54 mm	-	RS	881545 -2
41	1	U1	TSV994IDT	-	ST	TSV99 4IDT
42	1	U2	STGIPQ3H60T-HZ ST- SUPPLY	ST-SUPPLY	ST	STGIP Q3H60 T-HZ

UM2176 PCB design guide

10 PCB design guide

Optimization of PCB layout for high voltage, high current and high switching frequency applications is a critical point. PCB layout is a complex matter as it includes several aspects, such as length and width of track and circuit areas, but also the proper routing of the traces and the optimized reciprocal arrangement of the various system elements in the PCB area.

A good layout can help the application to properly function and achieve expected performance. On the other hand, a PCB without a careful layout can generate EMI issues, provide overvoltage spikes due to parasitic inductance along the PCB traces and produce higher power loss and even malfunction in the control and sensing stages.

In general, these conditions were applied during the design of the board:

- PCB traces designed as short as possible and the area of the circuit (power or signal) minimized to avoid the sensitivity of such structures to surrounding noise.
- Good distance between switching lines with high voltage transitions and the signal line sensitive to electrical noise.
- The shunt resistors were placed as close as possible to the low side pins of the SLLIMM. To decrease the parasitic inductance, a low inductance type resistor (SMD) was used.
- RC filters were placed as close as possible to the SLLIMM pins in order to increase their efficiency.

10.1 Layout of reference board

All the components are inserted on the top of the board. Only the IPM module is inserted on the bottom to allow the insertion of a suitable heatsink for the application.

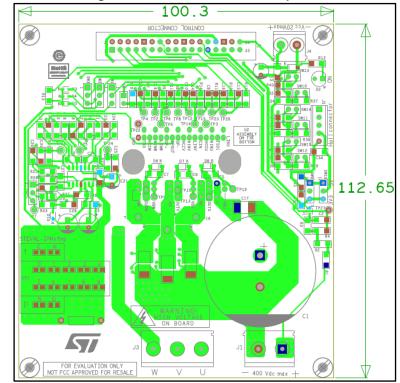


Figure 13: Silk screen and etch - top side

PCB design guide UM2176

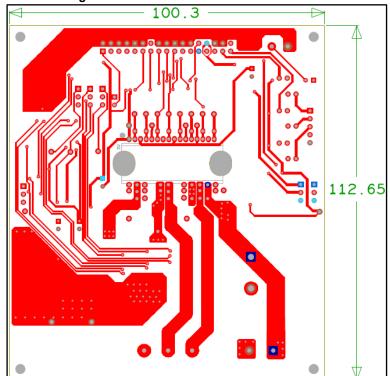


Figure 14: Silk screen and etch - bottom side

11 Recommendations and suggestions

- The BOM list is not provided with a bulk capacitor already inserted in the PCB. However, the necessary space has been included (C1). In order to obtain a stable bus supply voltage, it is advisable to use an adequate bulk capacity. For general motor control applications, an electrolytic capacitor of at least 100 µF is suggested.
- Similarly, the PCB does not come with a heat sink. You can place one above the IPM on the back side of the PCB with thermal conductive foil and screws. R_{TH} is an important factor for good thermal performance and depends on certain factors such as current phase, switching frequency, power factor and ambient temperature.
- The board requires +5 V and +3.3 V to be supplied externally through the 34-pin motor control connector J2. Please refer to the relevant board manuals for information on key connections and supplies.



12 General safety instructions



The evaluation board works with high voltage which could be deadly for the users. Furthermore all circuits on the board are not isolated from the line input. Due to the high power density, the components on the board as well as the heat sink can be heated to a very high temperature, which can cause a burning risk when touched directly. This board is intended for use by experienced power electronics professionals who understand the precautions that must be taken to ensure that no danger or risk may occur while operating this board.



After the operation of the evaluation board, the bulk capacitor C1 (if used) may still store a high energy for several minutes. So it must be first discharged before any direct touching of the board.



To protect the bulk capacitor C1, we strongly recommended using an external brake chopper after C1 (to discharge the high brake current back from the induction motor).

UM2176 References

13 References

Freely available on www.st.com:

- STGIPQ3H60T-HZ datasheet
- 2. TSV994 datasheet
- 3. BAT48 datasheet
- MMSZ5250B datasheet
- UM1052 STM32F PMSM single/dual FOC SDK v4.3 AN4840 SLLIMM™-nano 2nd series small low-loss intelligent molded module

Revision history UM2176

14 Revision history

Table 9: Document revision history

Date	Version	Changes	
02-Mar-2017	1	Initial release.	
17-May-2017	2	Updated Figure 1: "Motor control board (top view) based on SLLIMM-nano™ 2nd series" In Table 4: "ST motor control workbench GUI parameters - STEVAL-IPMNG3Q", changed current sensing block amplifying network gain parameter value to 1.9 (was 0.9)	
19-Sep-2017 3		Updated Section 1: "Key features", Section 4.3.2: "Shunt resistor selection" and Section 11: "Recommendations and suggestions".	

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